NSN 5961-01-121-1184

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-121-1184 **Inclosure Material:** Metal **Overall Length:** 0.625 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **End Application:** 4920-01-065-4907 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 repetitive peak reverse voltage and 100.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 8.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0